

# **PMV30ENEAR-VB Datasheet**

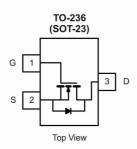
SOT23-3 Trench Single-N 40V MOSFET

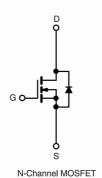
PRODUCT SUMMARY	
V <sub>DS</sub> (V)	40
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.035
$R_{DS(on)}$ ( $\Omega$ ) at $V_{GS} = 4.5 \text{ V}$	0.040
I <sub>D</sub> (A)	4.8
Configuration	Single

### **FEATURES**

- TrenchFET® Power MOSFET
- 100 % R<sub>g</sub> and UIS Tested







<b>ABSOLUTE MAXIMUM RATING</b>	<b>S</b> ( $T_C = 25$ °C, unles	s otherwise noted	d)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V <sub>DS</sub>	40	V	
Gate-Source Voltage		V <sub>GS</sub> ± 20		- V	
Continuous Drain Current	T <sub>C</sub> = 25 °C		4.8		
	T <sub>C</sub> = 125 °C	I <sub>D</sub>	3.6		
Continuous Source Current (Diode Conducti	ion)	Is	3.8	A	
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	20		
Single Pulse Avalanche Current		I <sub>AS</sub>	13		
Single Pulse Avalanche Energy	L = 0.1 mH	E <sub>AS</sub>	8	mJ	
Manian un Danier Disain ation?	T <sub>C</sub> = 25 °C	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	3	10/	
Maximum Power Dissipation <sup>a</sup>	T <sub>C</sub> = 125 °C				
Operating Junction and Storage Temperatur	re Range	T <sub>J</sub> , T <sub>sta</sub>	-55 to +175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount <sup>b</sup>	R <sub>thJA</sub>	166	°C/W
Junction-to-Foot (Drain)		R <sub>thJF</sub>	50	G/ <b>VV</b>

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. b. When mounted on 1" square PCB (FR-4 material).

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static					•		
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		40	-	-	V
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$		2.0	2.5	
Gate-Source Leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	0 V, V <sub>GS</sub> = ± 20 V	-	-	± 100	nA
Zero Gate Voltage Drain Current		V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 40 V	-	-	1	μА
	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V, T <sub>J</sub> = 125 °C	-	-	50	
		V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 40 V, T <sub>J</sub> = 175 °C	-	-	150	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = 10 V	V <sub>DS</sub> ≥ 5 V	10	-	-	Α
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 3.9 A	-	0.035	-	Ω
Dunin Course On State Besisteness		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 3.9 A, T <sub>J</sub> = 125 °C	-	0.045	-	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 3.9 A, T <sub>J</sub> = 175 °C	-	0.065	-	
		V <sub>GS</sub> = 4.5 V	I <sub>D</sub> =3.3 A	-	0.040	-	
Forward Transconductanceb	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> =3.9 A		-	30	-	S
Dynamic <sup>b</sup>					•		
Input Capacitance	C <sub>iss</sub>			-	442	553	
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 \text{ V}$ $V_{DS} = 20 \text{ V}, f = 1 \text{ MHz}$	1	79	99	pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			-	37	46	
Total Gate Charge <sup>c</sup>	Qg			-	8.7	13	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>GS</sub> = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 3.9 \text{ A}$	-	1.4	-	nC
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			-	1.6	-	
Gate Resistance	R <sub>g</sub>	f = 1 MHz		1.5	3.0	4.5	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			-	7.5	11	
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 20 \text{ V, } R_L = 20 \Omega$ $I_D \cong 1 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 1 \Omega$		-	8.4	13	ns
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>			-	12	18	
Fall Time <sup>c</sup>	t <sub>f</sub>			-	5.7	8.5	
Source-Drain Diode Ratings and Char-	acteristics <sup>b</sup>				,		
Pulsed Current <sup>a</sup>	I <sub>SM</sub>			-	-	32	Α
Forward Voltage	V <sub>SD</sub>	le =	5.4 A. V <sub>GS</sub> = 0 V	_	0.8	1.2	V

## Notes

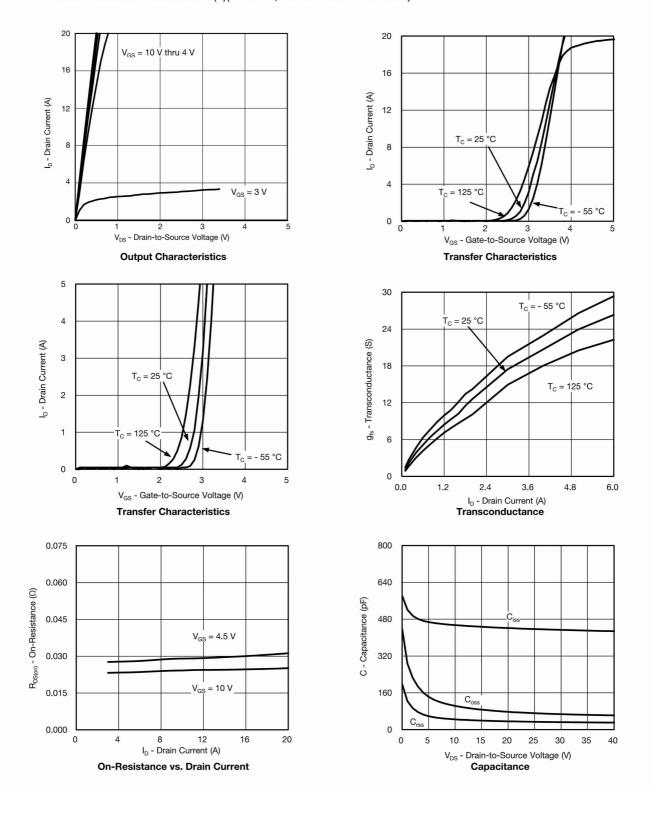
- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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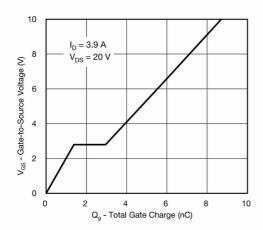


## **TYPICAL CHARACTERISTICS** ( $T_A = 25$ °C, unless otherwise noted)

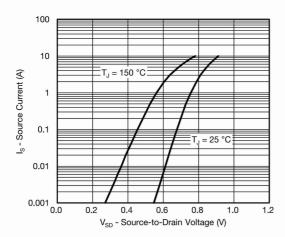




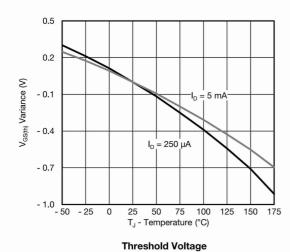
## TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



#### **Gate Charge**

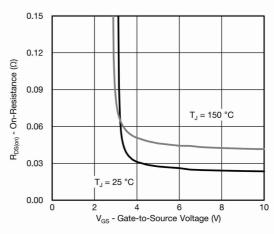


#### Source Drain Diode Forward Voltage

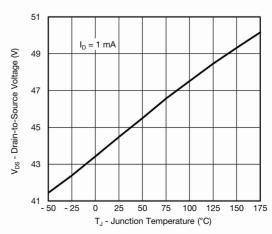


2.0

#### On-Resistance vs. Junction Temperature



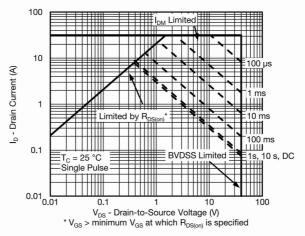
On-Resistance vs. Gate-to-Source Voltage



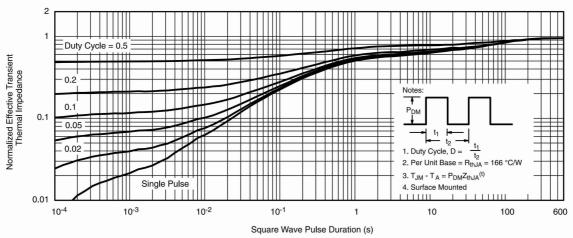
**Drain Source Breakdown vs. Junction Temperature** 



## **THERMAL RATINGS** ( $T_A = 25$ °C, unless otherwise noted)



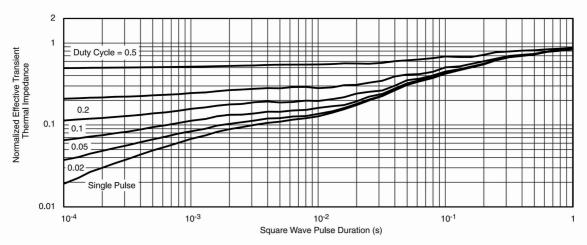
### Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



## **THERMAL RATINGS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



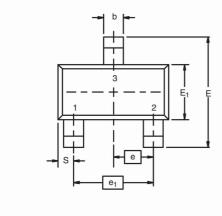
#### Normalized Thermal Transient Impedance, Junction-to-Foot

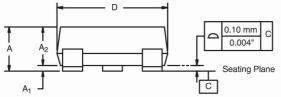
#### Note

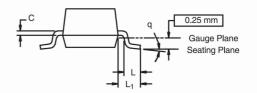
- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.









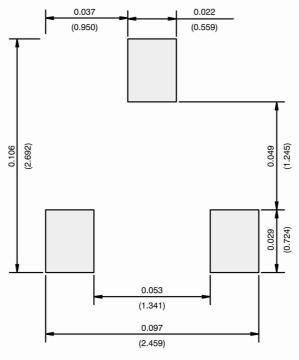
Dim	MILLIN	METERS	INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A <sub>1</sub>	0.01	0.10	0.0004	0.004	
A <sub>2</sub>	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E <sub>1</sub>	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e <sub>1</sub>	1.90 BSC		0.0748	3 Ref	
L	0.40	0.60	0.016	0.024	
L <sub>1</sub>	0.64 Ref		0.025	Ref	
s	0.50 Ref		0.020	Ref	
q	3°	8°	3°	8°	

DWG: 5479

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## **RECOMMENDED MINIMUM PADS FOR SOT-23**



Recommended Minimum Pads Dimensions in Inches/(mm)



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